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THz Near-Field Imaging of Extreme Subwavelength Metal Structures

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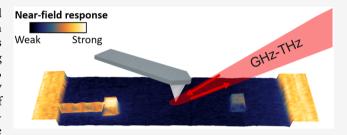
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ABSTRACT: Modern scattering-type scanning near-field optical microscopy (s-SNOM) has become an indispensable tool in material research. However, as the s-SNOM technique marches into the far-infrared (IR) and terahertz (THz) regimes, emerging experiments sometimes produce puzzling results. For example, "anomalies" in the near-field optical contrast have been widely reported. In this Letter, we systematically investigate a series of extreme subwavelength metallic nanostructures via s-SNOM near-field imaging in the GHz to THz frequency range. We find that the near-field material contrast is greatly impacted by the lateral size of



the nanostructure, while the spatial resolution is practically independent of it. The contrast is also strongly affected by the connectivity of the metallic structures to a larger metallic "ground plane". The observed effect can be largely explained by a quasi-electrostatic analysis. We also compare the THz s-SNOM results to those of the mid-IR regime, where the size-dependence becomes significant only for smaller structures. Our results reveal that the quantitative analysis of the near-field optical material contrasts in the long-wavelength regime requires a careful assessment of the size and configuration of metallic (optically conductive) structures.

KEYWORDS: scattering-type scanning near-field optical microscopy (s-SNOM), near-field, THz, nanoimaging, Schottky diodes

he best spatial resolution that can possibly be achieved with a conventional optical microscope is fundamentally constrained by the diffraction limit to roughly half of the incident wavelength, prohibiting nanoscale optical characterization. In an effort to overcome this limit, the scattering-type scanning near-field optical microscope (s-SNOM) was developed. The tip-scattered light conveys local sample information and is detected by a conventional far-field detector. In this case, the spatial resolution is determined predominantly by the tip apex radius, tapping amplitude, and demodulation order, and as such is essentially independent of the incident wavelength. Since its introduction, s-SNOM nanoimaging and spectroscopy have aided numerous scientific advances such as direct spatial mapping of surface polaritons, spatial phase coexistence, and electromagnetic field localization.3

The spectral region spanning 0.1–10 terahertz (THz) is commonly recognized as the "THz gap" because of technical difficulties in the generation and detection of intense coherent THz light. Performing s-SNOM at THz frequencies poses even greater challenges: conventional AFM probes are extreme subwavelength objects, resulting in low coupling and scattering efficiency. Nevertheless, intense research efforts by the THz s-SNOM community have led to significant technical and instrumental advances in recent years, 13–26 enabling nanoimaging in the 50 GHz to 5 THz spectral region for accessing local conductivity and phase coexistence.

The deep-subwavelength scale spatial resolution achievable via s-SNOM can be largely attributed to the tight electromagnetic field confinement below the tip apex.^{27,28} This fact sometimes leads to the misconception that the near-field optical contrast is solely governed by the optical properties, i.e. dielectric constants or optical conductivity, of the sample volume right under the tip apex. However, recent THz s-SNOM experiments provide some contradicting and counterintuitive yet fundamentally interesting observations. For example, it has been reported that isolated metallic structures exhibit a lower near-field contrast compared to large and connected ones, even though the spatial resolution of THz s-SNOM is much higher than the structure size.²² It has also been reported that AFM tips with larger apex radii increase the THz near-field amplitude and contrast, while leaving the spatial resolution nearly unaffected.²⁸ In this Letter, we describe systematic THz and mid-IR near-field imaging of a series of metallic nanostructures. These findings suggest that in addition to intrinsic material properties, the size and configuration of

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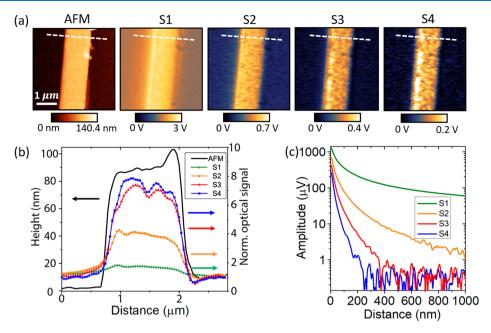


Figure 1. Assessment of spatial resolution and signal-to-noise ratio obtained via THz s-SNOM. (a) Left to right: AFM topographic image and near-field images demodulated at different harmonics of the tip's tapping frequency. (b) Height and near-field optical signal profiles along the white dashed lines in (a). S1 through S4 are normalized to the average substrate signal in their corresponding images to yield a relative contrast. (c) Approach curves for different orders of demodulation on gold bar.

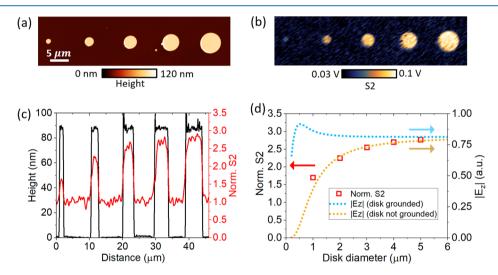


Figure 2. (a) AFM image of a series of micron-sized gold disks. (b) The corresponding second harmonic near-field amplitude image at 171.84 GHz (1.74 mm), which shows an increasing near-field response with increasing disk diameter. (c) Height and normalized near-field S2 optical signal profiles across the disks in (a) and (b). The height of the disk is constant (~80 nm), while S2 increases with increasing disk diameter. (d) Red squares: average and normalized near-field signal (S2) of the disks with different diameters. Brown and blue curves represent the calculated electric field at the point charge for ungrounded and grounded disks, respectively.

the probed nanostructure in the deep subwavelength regime plays important roles for near-field optical material contrasts.

We first use a home-built s-SNOM setup to perform sub-THz near-field imaging. The system utilizes high-harmonic (12th) generation from a microwave source. 15,25 A signal generator produces a microwave signal (9–14.6 GHz), which is then frequency multiplied through Schottky diodes. This generates a coherent sub-THz wave (110–175 GHz), which is directly focused onto the tip of an atomic force microscope (AFM; Bruker Multimode). The AFM is operating at tapping mode with frequency Ω . The second signal generator supplies microwave radiation at a slightly different frequency to another Schottky diode, which functions as both the detector and the

reference light generator. The frequency difference between the incident light and the reference light is set to be $\Delta\Omega=24$ MHz. The second Schottky diode is connected to a Lock-in amplifier (Zurich HF2LI), which demodulates the signal at $n\Omega-m\Delta\Omega$ as an mean of phase-resolved imaging and far-field background suppression. To improve the light coupling efficiency between the THz wave and the AFM tip, we use customized tips (Rocky Mountain Nanotechnology, LLC) of length about 200 μm and apex radius about 100 nm. The tips are longer and have a larger apex radius compared to typical AFM tips used for IR or visible s-SNOM, thus, greatly enhancing the THz scattering and improving the signal-tonoise ratio. All of our THz s-SNOM experiments use a

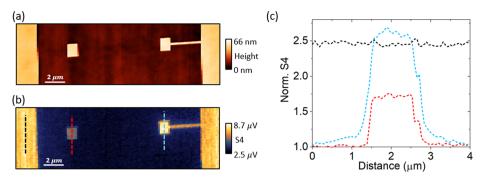


Figure 3. (a) AFM topography image of an isolated gold square patch and a connected gold square patch. (b) The corresponding fourth harmonic near-field image (S4) at 2.52 THz ($119 \mu m$). (c) Normalized near-field S4 profiles along the indicated dashed lines in (b). The black curve is across the large gold pad. The blue curve is across the connected gold patch. The red curve is across the isolated gold patch.

typical tapping frequency of $\Omega \sim 40$ kHz with a tapping amplitude around 100 nm.

We first characterize the spatial resolution of our THz s-SNOM setup via imaging a \sim 90 nm thick by \sim 1.5 μ m wide gold bar antenna on a SiO2 substrate. AFM topography and near-field amplitude images demodulated at the first (S1), second (S2), third (S3), and fourth (S4) harmonic orders are shown in Figure 1a. A clear material contrast between gold and SiO₂ is observed in all of the demodulated near-field amplitude images. Height and near-field optical signal profiles across the bar (designated by the white dashed lines) are displayed in Figure 1b. The near-field amplitude signals are normalized to the averaged substrate signal. The near-field optical resolution is similar to the AFM resolution and is mainly limited by the AFM tip apex radius. When a topographic boundary is present, it is difficult to precisely evaluate the optical resolution due to the unknown slope of the edge and edge-darkening artifact.³⁰ However, based on the edge profile of the optical signal, we conservatively estimate that the resolutions for AFM and S2 to be 120 and 200 nm based on 90 to 10% signal width, similar to previously reported spatial resolution of THz s-SNOM and other microwave scanning probe techniques. 31,32 Nonetheless, we achieved a near-field resolution in the order of $\lambda/10^4$ with second harmonic demodulation at ~100 GHz range. Note that the relative contrast in the S1 image is rather weak due to an undesirable far-field background signal, which is confirmed by the approach curves in Figure 1c, wherein the S1 approach curve does not significantly subside even at a tip-sample distance of 1 μ m, while the S2-S4 curves quickly decay. Similar to typical IR s-SNOMs, demodulation up to at least the second harmonic order is necessary in order to effectively suppress the background. Furthermore, statistical analysis of the signal variation on gold indicates that the S2 signal-to-noise ratio is at least 10:1. The optical signals appear to be slightly higher on the left side of the gold bar. We attribute this to a scanning induced artifact due to the uneven surface of the

Next we demonstrate that the near-field material contrast of s-SNOM depends strongly on the size of the metallic structures, although the spatial resolution is nearly independent of the structure size. We first study gold disks of diameters from 1 to 5 μ m, fabricated on a SiO₂ substrate (AFM image shown in Figure 2a). From common knowledge one could assume an identical near-field material contrast for all disks, except for cases in which antenna effects or polaritonic responses occur (which is not the case here, as disks are of deep subwavelength scale). However, the THz s-SNOM

amplitude images show a clear decrease of the near-field amplitude signal of the disk with decreasing disk diameter (Figure 2b). Line profiles across the disk centers (Figure 2c) show the effect more clearly. Note that even the smallest disk size (1 μ m diameter) is much larger than the spatial resolution. Only the S2 images are displayed without loss of generality because the S3 and S4 images show the same trend. A qualitatively similar phenomenology has been experimentally observed with scanning probe technique combined with difference-frequency generation where the frequency difference between two incident CO_2 lasers (both at ~10 μ m wavelength) is set to 9 GHz. 33,34 The authors observed difference-frequency generation signal from the metallic disks with different sizes. They postulated that the disk-sizedependent difference-frequency generation signal is related to the periodic charge distributions on the tip and the disks induced by the incident radiations at $\sim 10 \,\mu m$ wavelength. This is not applicable in our case because the incident wavelength used in our experiments is orders of magnitude larger than the length of the tip shank and the disk diameter such that the spatially periodic charge distribution is unlikely to form.

Inspired by previous works on electrostatic force microscopy, 35,36 we propose an electrostatic "toy-model" for our experimental data. The electrostatic limit is justified due to the much longer incident wavelength compared to the size of the tip and the nanostructures. For simplicity, we model the tip by an electrical monopole with charge q located near the tip apex. Then the electrostatic problem of a point charge above a conducting disk can be solved analytically with a clean solution. Suppose the point charge is located at $(0, 0, z_0)$ above the center of a grounded metal disk of radius a in the x-y plane, the potential on the z axis due to both the point charge and the induced surface charge on the disk is given by 38

$$V_1(z) = \frac{2q}{\pi(z^2 - z_0^2)} \left[z_0 \tan^{-1} \left(\frac{a}{z} \right) - z \tan^{-1} \left(\frac{a}{z_0} \right) \right]$$
 (1)

If the disk is not grounded, its potential picks up an extra term due to the presence of balancing charges with opposite sign (to make sure the disk is charge neutral) and becomes

$$V_2(z) = V_1(z) + \frac{2q}{a\pi} \tan^{-1} \left(\frac{a}{z}\right) \tan^{-1} \left(\frac{a}{z_0}\right)$$
 (2)

In Figure 2d, we calculate the trend of the electric field at the position right below the monopole $|E_z(z_0\approx 250 \text{ nm})|=|-\frac{\mathrm{d}V(z)}{\mathrm{d}z}\Big|_{z=z_0}|\text{ as a function of disk}$

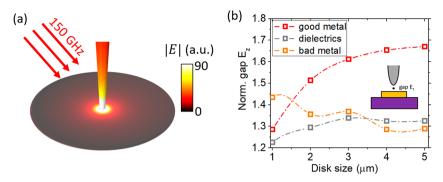


Figure 4. (a) Simulation geometry and typical electric field distribution. (b) Normalized electric field in the tip-sample gap as a function of disk diameter for three categories of material: a good metal ($\varepsilon_1 \to -\infty$, $\varepsilon_2 \to \infty$), a dielectric material ($\varepsilon_1 = 10$, $\varepsilon_2 = 0.1$), and a bad metal ($\varepsilon_1 = -10$, $\varepsilon_2 = 10$).

diameter d for both grounded (blue curve) and ungrounded (brown curve) scenarios. The balancing charge in the case of ungrounded disks is found to be of significant importance for the change of the electric field, which is consistent with the size dependent trend of the averaged S2 signal of the disks (red squares in Figure 2d). On the other hand, when the disk is grounded, the electric field is predicted to be constant at d > 1 μ m, as we demonstrate below.

In an earlier THz nanoimaging work by Kuschewski et al., small and isolated gold islands have been observed to exhibit a lower near-field signal compared to large and connected islands.²² This was attributed phenomenologically to the weaker polarizability of the small isolated islands. Here using the electrostatic model, we can provide quantitative insights into this intriguing observation. As suggested by eq 1 and the blue curve in Figure 2d, if the condition of local charge neutrality is broken by connecting the small disks to the ground or a large gold pad (as a charge reservoir), the nearfield signal will be significantly boosted. To test this effect, nanoimaging is performed on two identical gold square patches, with one isolated and the other connected to a large gold pad (Figure 3). Here we use a commercial s-SNOM (Neaspec GmbH, Germany) with a tunable THz gas laser (SIFIR-50, Coherent Inc., U.S.A.) operating at 2.52 THz. The scattered light is collected interferometrically in a homodyne scheme by a cryogen-free THz bolometer (QMC Instruments Ltd., Cardiff, U.K.). Simultaneously obtained AFM topography and fourth harmonic near-field amplitude image are shown in Figure 3a,b. Corresponding line profiles across the gold patches and large gold pad are shown in Figure 3c. Despite the fact that two gold patches have the same thickness ~50 nm and lateral size $\sim 1 \mu m$, the near-field responses are drastically different. The connected gold patch exhibits a significantly stronger near-field signal (S4) than the isolated one, even slightly stronger than the large gold pad. This observation is consistent with the expectation and supports the validity of our electrostatic analysis. This result can also be directly compared to the work by Kuschewski et al.²²

Overall, our phenomenological model yields a qualitative interpretation of the observed phenomenon. However, we postulate that the underlying physics can be much more complex. Besides the above-described effect, other effects may be responsible for the observed size-dependent near-field contrast which deserves further investigation. For example, beyond the electrostatic limit, surface inductance is found to be weakened in smaller metallic structures. The decreased inductance leads to a relatively more important contribution

from the disk resistance, which leads to a higher eddy current damping in the near-field. This may greatly reduce the electric field intensity thus the near-field scattering signal (this analysis will be reported by S. T. Chui elsewhere).

While a full analytical electrodynamic model remains challenging, full-wave simulations of the tip-disk-substrate system are more probable and can be carried out using the finite element method (COMSOL). The scale mismatch among incident wavelength (1.74 mm), tip length (200 μ m), and tip-sample distance (0-100 nm) makes a rigorous simulation of the near-field signal computationally expensive. 28,30,39-41 Instead, we use the electric field enhancement factor (electric field normalized to incident field) inside the tip-sample gap as an indirect gauge for the near-field interaction, a well-established approach within the community. It was recently demonstrated that the local field enhancement does not necessarily reflect the scattering intensity when the tip radii are different.²⁸ For example, enlarging a tip radius results in weaker local field enhancement even though it also makes the scattering intensity much higher. However, for a constant tip radius, the field enhancement and detected near-field signal are expected to be positively correlated.²⁷ Here we simulate the total electric field enhancement under the tip volume by modeling the tip as a cone of 200 μ m shank length and 100 nm radius at its bottom, which resembles realistic tip geometry. The disk on the SiO₂ substrate is set to be 100 nm beneath the tip apex. An incident plane wave of 150 GHz frequency approaches the sample at a 60° angle with respect to the surface normal.

The simulation layout and typical electric field distribution are shown in Figure 4a. The field inside the gap between the tip and the disk is closely monitored as the disk size increases from 1 to 5 μ m. To extend the generality of the simulation, we test three categories of material by adjusting the disk permittivity $\varepsilon = \varepsilon_1 + i\varepsilon_2$ for a good metal $(\varepsilon_1 \to -\infty, \varepsilon_2 \to \infty)$, a dielectric material $(\varepsilon_1 = 10, \varepsilon_2 = 0.1)$, and a bad metal $(\varepsilon_1 = -10, \varepsilon_2 = 10)$. Field enhancement normalized to that of a "vacuum disk" $(\varepsilon_1 = 1, \varepsilon_2 = 0)$ as a function of disk diameter is shown in Figure 4b. Of the three materials, only the good metal exhibits a significant, monotonically increasing field enhancement, as is consistent with our experimental observations. The field enhancements of the dielectric materials and bad metals are noticeably less affected by increasing disk diameter due to the lack of mobile charge carriers

From the simulations, we conclude that the aforementioned size-dependent, near-field contrast is most prominent in good

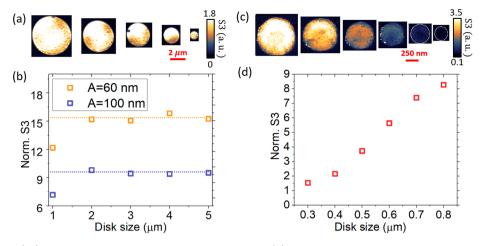


Figure 5. (a) Near-field (S3) images on disks of diameter 1, 2, 3, 4, and 5 μ m. (b) Average S3 contrast as a function of disk diameter. The dashed lines indicate the saturation signal level. A is the tip tapping amplitude. (c) Near-field (S3) images of disks of diameter 300, 400, 500, 600, 700, and 800 nm. White circles indicate the boundaries of the disks. (d) Average S3 contrast as a function of disk diameter. The dashed line indicates a linear trend.

metals, which have significant surface charge or current. The THz near-field signals of dielectrics or bad metals should not exhibit significant dependence for sample sizes at the micron scale ($\sim \lambda/100$). Unfortunately, the scale mismatch between the wavelength (~ 2 mm), tip length ($\sim 200~\mu m$), disk diameter ($\sim 1~\mu m$), and the tip apex radius (100 nm) currently prevents us from performing further systematic simulations to investigate the fine details of the tip–sample scattering process, such as the emission pattern, charge distribution, and dipole moment of the tip. These aspects remain to be studied when time and computation power allow in the future.

For comparison, we examine the size-dependent near-field material contrast in the mid-IR regime. Near-field imaging at ~6 µm wavelength is performed via a commercial s-SNOM (Neaspec GmbH, Germany) equipped with a quantum cascade laser (Daylight Solutions, U.S.A.). Figure 5a shows S3 amplitude images of the same gold disks previously studied. Compared to the THz near-field images, no significant sizedependence is observed in the optical response of the mid-IR images for disks larger than 1 μ m. An average near-field contrast as a function of disk size is plotted in Figure 5b for two different tapping amplitudes. Increasing the tapping amplitude diminishes the overall contrast, but has no significant effect on the trend of the optical response versus disk size. Unlike the sub-THz near-field signal, that of mid-IR quickly saturates when the disk size exceeds 1 μ m. We further investigate by studying smaller disks of diameter 300-800 nm, whose responses quickly decay with decreasing disk size, as shown in Figure 5c,d. The trend can still be phenomenologically fitted by the quasi-electrostatic analysis in eq 1 with a smaller charge-disk distance z_0 , but the much shorter wavelength of mid-IR radiation, in principle, makes the quasi-electrostatic assumption quantitatively invalid. A similar analysis with consideration of the retardation should be more appropriate, but it is beyond the scope of this work since a simple analytical form cannot be easily obtained, and not much more physical insight is gained from such a treatment.

To demonstrate that this phenomenon is not limited to a particular frequency, mid-IR broadband near-field spectroscopy is performed on the same disk samples. Indeed, a similar trend is observed in the whole frequency range between 400 and 1100 cm⁻¹ (Supporting Information, S2). Furthermore,

we find that demodulation order also has a minimal impact on trend of the near-field contrast (Supporting Information, S3).

In the end, we would like to note that, in some of the gold disks, mid-IR nanoimaging reveals plasmonic patterns that are spatially inhomogeneous. This is because the sizes of these disks are comparable to the incident wavelength where the antenna effect is prominent.^{39,42–44} Similar antenna effect is absent in the THz nanoimages due to the scale mismatch. To our best knowledge so far, there is only one published report on THz near-field imaging of the antenna effects using s-SNOM.⁴⁵ Further investigations still await.

Without considering polaritonic or antenna effects, current understanding of s-SNOM suggests that the near-field material contrasts are determined by the local dielectric properties of the sample and data acquisition parameters (tip radius, tapping amplitude, demodulation order, etc.). Therefore, theoretical attempts to calculate the near-field contrast typically model the sample as a homogeneous semi-infinite half-space^{2,46-49} or layered planes, 50,51 neglecting lateral inhomogeneity. These assumptions are largely valid for samples of bad metals or dielectric insulators. 52,53 However, our study shows that in metallic structures smaller than $\sim 1/100 \ \lambda$ in the THz region and $\sim 1/10 \lambda$ in the IR region, the sample size can significantly affect the near-field contrast and demands further theoretical investigations. Together with previous reports^{54–56} demonstrating the IR near-field resonance effect in metallic structures of size $\sim 1/10 \ \lambda$ to $\sim 1 \ \lambda$, this work suggests that geometric factors in metals are indeed important and need to be carefully addressed in the nanoimaging process with s-SNOM.⁴²

ASSOCIATED CONTENT

Supporting Information

The Supporting Information is available free of charge at https://pubs.acs.org/doi/10.1021/acsphotonics.9b01534.

S1: THz nanoimaging on linear antennas with different lengths; S2: Mid-IR broadband spectroscopy on gold disks; S3: Effect of demodulation order on near-field contrast (PDF)

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Notes

The authors declare the following competing financial interest(s): R.H. is a co-founder of Neaspec GmbH, a company producing scattering-type scanning near-field optical microscope systems such as the one used in this study. The other authors declare no competing interests.

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